TOSHIBA Photocoupler Photorelay

TLP206GA

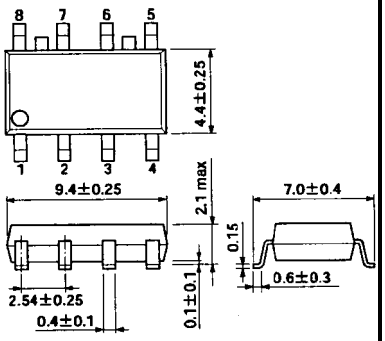
PBX

Telecommunication

Modem・FAX Cards, Modems In PC

Measurement Instrumentation

Unit: mm



JEDEC	—
JEITA	—
TOSHIBA	11-10H1

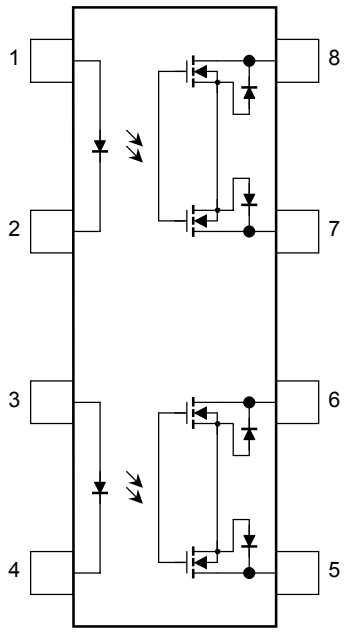
Weight: 0.2 g (typ.)

The TOSHIBA TLP206GA consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET in a SOP, which is suitable for surface mount assembly.

The TLP206GA is a 2-Form-A switch, which is suitable for replacement of mechanical relays in many applications.

- 8 pin SOP (2.54SOP8): 2.1 mm high, 2.54 mm pitch
- 2-form-A
- Peak off-state voltage: 400 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 120 mA (max)
- On-state resistance: 35 Ω (max)
- Isolation voltage: 1500 Vrms (min)

Pin Configuration (top view)



1, 3: ANODE
2, 4: CATHODE
5: DRAIN D1
6: DRAIN D2
7: DRAIN D3
8: DRAIN D4

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
LED	Forward current	I_F	50	mA
	Forward current derating (Ta ≧ 25°C)	ΔI_F/°C	−0.5	mA/°C
	Peak forward current (100 μs pulse, 100 pps)	I_{FP}	1	A
	Reverse voltage	V_R	5	V
	Junction temperature	T_j	125	°C
Detector	Off-state output terminal voltage	V_{OFF}	400	V
	On-state current	I_{ON}	120	mA
	On-state current derating (Ta ≧ 25°C)	ΔI_{ON}/°C	−1.2	mA/°C
	Junction temperature	T_j	125	°C
Operating temperature range		T_{opr}	−40 to 85	°C
Storage temperature range		T_{stg}	−55 to 125	°C
Lead soldering temperature (10 s)		T_{sol}	260	°C
Isolation voltage (AC, 1 min, R.H. ≦ 60%) (Note 1)		BV_S	1500	Vrms

Note 1: Device considered a two-terminal device: LED side pins shorted together, and DETECTOR side pins shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min	Typ.	Max	Unit
Supply voltage	V_{DD}	—	—	320	V
Forward current	I_F	5	7.5	25	mA
On-state current	I_{ON}	—	—	120	mA
Operating temperature	T_{opr}	−20	—	65	°C

Individual Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
LED	Forward voltage	V_F	I_F = 10 mA	1.0	1.15	1.3	V
	Reverse current	I_R	V_R = 5 V	—	—	10	μA
	Capacitance	C_T	V = 0, f = 1 MHz	—	30	—	pF
Detec-tor	Off-state current	I_{OFF}	V_{OFF} = 400 V	—	—	1	μA
	Capacitance	C_{OFF}	V = 0, f = 1 MHz	—	70	—	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Trigger LED current	I_{FT}	I_{ON} = 120 mA	—	1	3	mA
Return LED current	I_{FC}	I_{OFF} = 100 μA	0.1	—	—	mA
On-state resistance	R_{ON}	I_{ON} = 120 mA, I_F = 5 mA	—	17	35	Ω

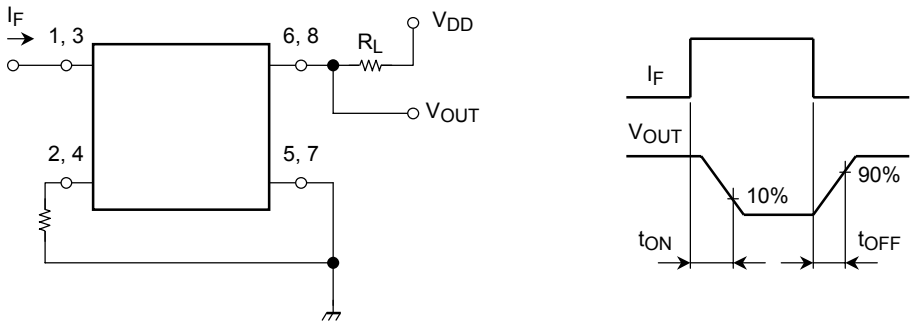
Isolation Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Capacitance input to output	C_S	V_S = 0, f = 1 MHz	—	0.8	—	pF
Isolation resistance	R_S	V_S = 500 V, R.H. ≦ 60%	5×10^{10}	10^{14}	—	Ω
Isolation voltage	BV_S	AC, 1 min	1500	—	—	Vrms
		AC, 1 s, in oil	—	3000	—	
		DC, 1 min, in oil	—	3000	—	Vdc

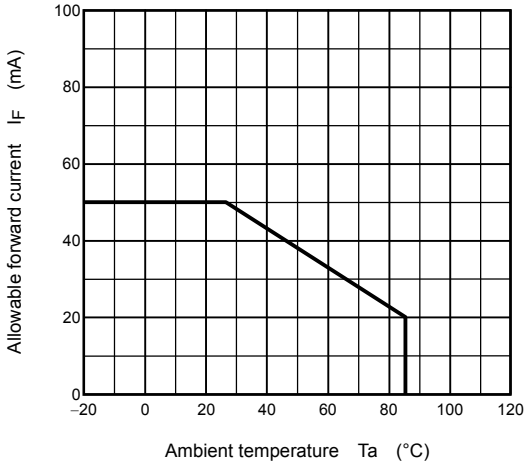
Switching Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Turn-on time	t_{ON}	R_L = 200 Ω (Note 2)	—	0.3	1	ms
Turn-off time	t_{OFF}	V_{DD} = 20 V, I_F = 5 mA	—	0.1	1	ms

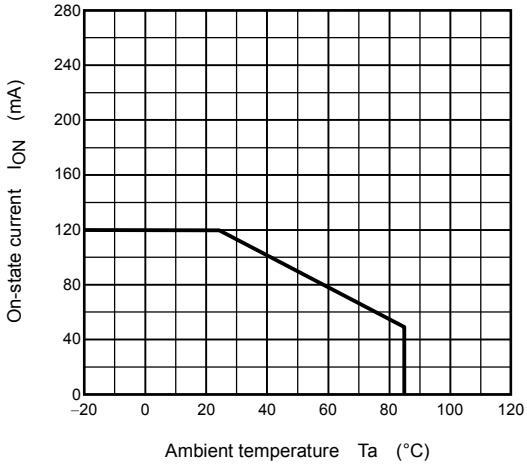
Note 2: Switching time test circuit



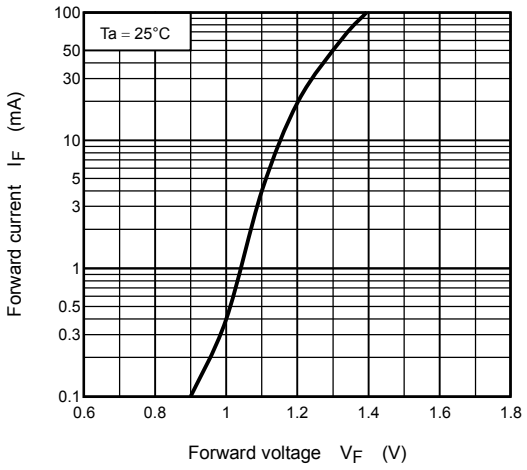
I_F – Ta



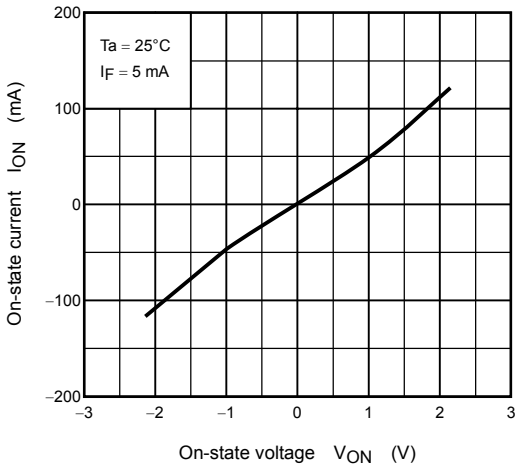
I_{ON} – Ta



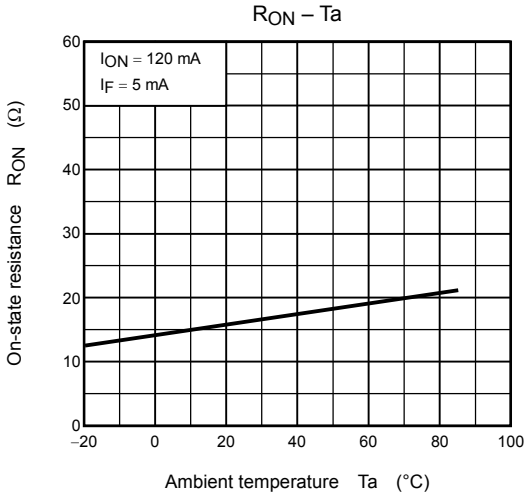
I_F – V_F



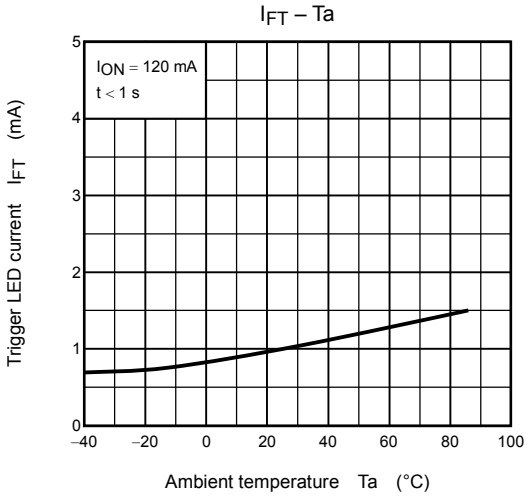
I_{ON} – V_{ON}



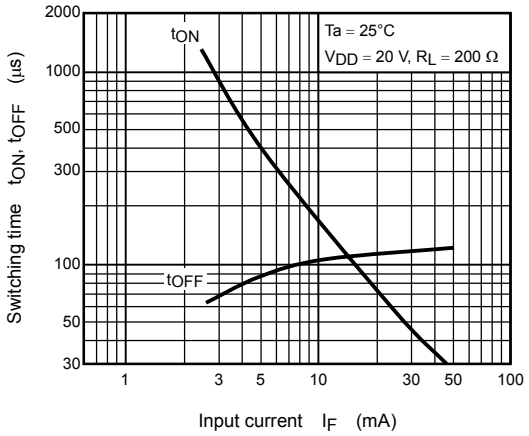
R_{ON} – Ta



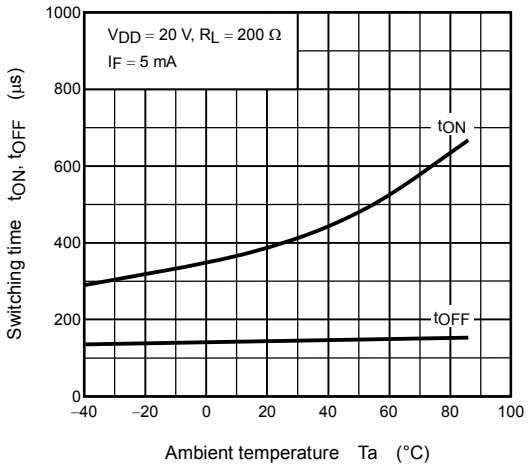
I_{FT} – Ta



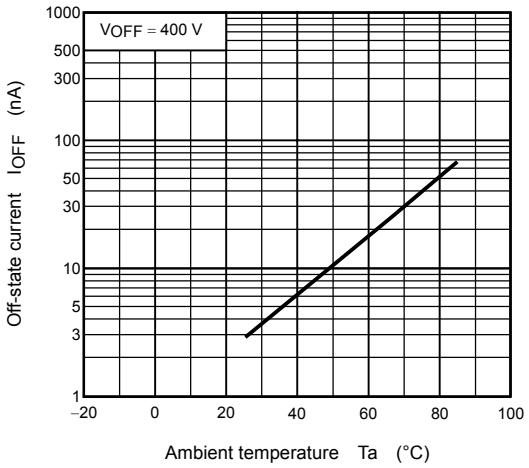
t_{ON}, t_{OFF} – I_F



t_{ON}, t_{OFF} – Ta



I_{OFF} – Ta



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